

捷多邦,专业PCB打样工厂 _,24小时加急出货

AM Receiver for AM Stereo

Preliminary Data

Features

- Internal demodulation
- Search tuning stop signal
- Low total harmonic distortion
- Minimal IF leakage at the AF output
- 2-stage integrated low pass
- Standard IF-output

Туре	Ordering Code	Package
TDA 4010	Q67000-A8074	P-DIP-18

TDA 4010 Bipolar IC

Circuit Description

Compared to TDA 4001 the TDA 4010 is an extended AM-receiver. This type is suitable for applications in car radios.

The IF-output Vor is at pin 15.

The monolithic integrated bipolar receiver has been designed to convert, amplify and demodulate AM-signals. In addition, the component provides a search tuning pulse.

The search tuning stop pulses are processed from the input signal.

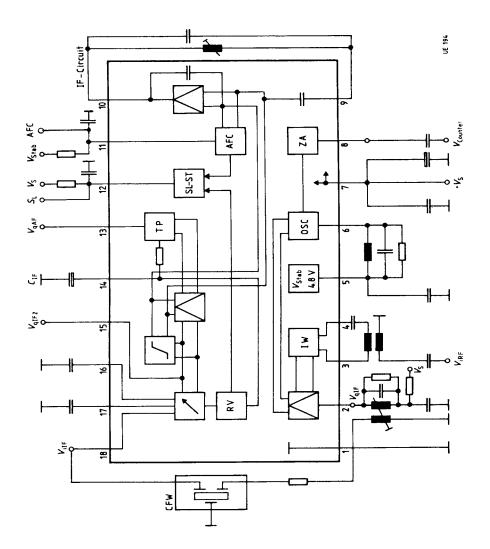
The standard AM-IF signal is available at the output of the IF-receiver.

The impedance converter forwards the input signal V_{IRF} to the symmetrical double balanced mixer. Subsequently the signal is converted to IF with the amplitude-controlled oscillator. An external filter forwards the IF signal to the controlled IF amplifier. The amplifier IF signal and the carrier signal will be converted to AF in the subsequent synchronous demodulator. The 2-stage low pass filter forwards the available AF to the AF output.

Via an additional limiter amplifier (LA), the AF uses the carrier signal to control the coincidence demodulator (CD). The output signal of the coincidence demodulator provides the stop pulse during exact tuning and sufficient field strengh.



Block Diagram



Pin Functions

Pin No.	Function
1	Ground
2	Mixer output, IF circuit
3	RF-input
4	RF-input
5	V Stab
6	Oscillator
7	Supply voltage
8	Counter output
9	FM-demodulator circuit IF circuit
10	FM-demodulator circuit IF circuit
11	AFC-output
12	Search tuning stop output
13	AF-output
14	IF-time constant
15	Controlled IF-output
16	IF-operating point follow up device
17	IF-operating point follow up device
18	IF-input

Absolute Maximum Ratings $T_A = 25 \degree C$

Parameter	Symbol	Liı	Unit	
		min.	max.	
Operating voltage	Vs		16.5	V
Current consumption	<i>I</i> s		33	mA
Junction temperature	Ti		150	°C
Storage temperature	Tstg	- 40	125	°C

Thermal Resistance

Chip ambient	R th SU	78	K/W
Chip package	R th SG		

Operating Range

Operating voltage	Vs	7	15	V
Temperature range	TA	- 25	85	°C

Characteristics Vs = 12 V; T_A = 25 °C

Parameter	Sym-	Limit Values			Unit	Test Condition
	bol	min.	typ.	max.		
Current consumption	/s	9	15	30	mA	
Reference voltage	VStab	4.2	4.8	5.4	V	
IF-output voltage	Vqıf	600	800 300	1000	mVrms mVrms	m = 0.8 m = 0.3
Total harmonic distortion	THD	<i>m</i> = 0.8		2.5 1	% %	m = 0.8 m = 0.3
IF-output voltage	VQIF			3	dB	20xlg(Vanf/30mV0: Vanf/1mV)
Input sensitivity	VIRF	30	30		μV rms	V_{qNF} for $V_{iHF} = 1 \text{mV} - 3 \text{dB}$
Signal-to-noise ratio	$\frac{S+N}{N}$		6		dB	m = 0.3 ViHF = 10 μVrms
Signal-to-noise	S + N	44	46		dB	<i>m</i> = 0.3 <i>V</i> _{iHF} = 1mV
Oscillator voltage	Vosc		100		mV pp	
Counter output volt- age	Vac			100	mV pp	
Control range ($\Delta V_{qIF} = 6dB$)	a	60			dB	
3dB limit frequency of the integrated TP	fg		5		kHz	

Characteristics (cont'd) $V_{s} = 12 \text{ V}; T_{A} = 25 \degree \text{C}$

Parameter	Sym-			Jes Unit		Test Condition
	bol	min.	typ.	max.	-	
IF-suppresion	<i>a</i> if		40		dB	
Conversion gain	Vm		30		dB	
IF-output pin 15	V QIF	8	10	22	mV rms	1MΩ/1.5pF
AFC-offset current without signal	IAFC			± 25	μA	
AFC-offset current over control range	ΔÍAFC			± 25	μΑ	
AFC-current	I AFC	± 60		± 100	μA	<i>f</i> ⊪ = 1MHz ± 3kHz
SLS-output voltage	V 12			0.4	V	<i>f</i> ⊪ = 455kHz
SLS-output voltage	V12	11			V	$f_{\rm IF}={\rm OV}$
SLS-output voltage	V12	11			V	<i>f</i> ı⊧ > 455kHz + 3kHz
SLS-output voltage	V 12	11			V	<i>f</i> ı⊧ > 455kHz – 3kHz
Input impedance	Zirf		10/1.5		kΩ//pF	pin 3, 4
Input impedance	ZIRF		3.3/1.5		kΩ//pF	pin 18

UE 195

o V_{Counter}

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† ₽ 2 1F - <u>Circuit</u> 1-00r ┿ 22⊮+ 47nF 헏 6 AFC 10kΩ V_{Stab} AFC ۲A F æ ŝ Ë SL-ST ŧ 4 12 100n + Ś ₹° 4 osc f 6 115 turns 82 pF 8kΩ ±22μF V_{Stab} 4.8 V اٿ 14 ŝ =100nF 7.9 2150 £ +100nF ++100nF =100nF ١ 5 <u>S</u> žγ 560Ω Š = 100nF 5 22 11 Š, 18 76:26 trn. 1.5kΩ ΓV

Test Circuit